VS-UFL80FA60

Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 80 A



PRIMARY CHARACTERISTICS						
V _R	600 V					
$I_{F(AV)}$ per module at $T_C = 115 \text{ °C}$	80 A					
t _{rr}	41 ns					
Туре	Modules - diode FRED Pt [®]					
Package	SOT-227					

FEATURES

- Two fully independent diodes
- · Fully insulated package
- Ultrafast, soft reverse recovery, with high RoHS COMPLIANT operation junction temperature (T_{.1} max. = 175 °C)
- Low forward voltage drop
- · Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- UL approved file E78996
- Designed and gualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

The VS-UFL80FA60 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V _R		600	V			
Continuous forward current per diode	I _F	T _C = 85 °C	65	٨			
Single pulse forward current per diode	I _{FSM}	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	300	A			
Maximum power dissipation per module	PD	T _C = 85 °C	176	W			
RMS isolation voltage	VISOL	Any terminal to case, t = 1 min	2500	V			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			







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ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST COND	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	600	-	-		
Forward voltage	V _{FM}	I _F = 30 A	-	1.1	1.43		
		I _F = 60 A		-	1.27	1.49	V
		I _F = 30 A	T 105 %O	-	1.0	1.23	
		I _F = 60 A	T _J = 125 °C	-	1.17	1.35	
Devenue la classe commente		V _R = V _R rated		-	0.1	50	μA
Reverse leakage current	I _{RM}	$T_J = 175 \text{ °C}, V_R = V_R \text{ rated}$		-	0.2	1.0	mA
Junction capacitance	CT	V _R = 600 V		-	30	-	pF

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time	very time t _{rr}		$ I_F = 1 \text{ A}; \\ dI_F/dt = 200 \text{ A}/\mu\text{s}; \\ V_R = 30 \text{ V} $	-	41	-	ns	
nevelse recovery time	۲r	T _J = 25 °C	I _F = 30 A dI _F /dt = 200 A/μs V _R = 200 V	-	115	-	115	
		T _J = 125 °C		-	200	-		
Deale receiver a current	1	T _J = 25 °C		-	11	-	٨	
Peak recovery current	IRRM	T _J = 125 °C		-	20	-	A	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	600	-	nC	
		T _J = 125 °C		-	1900	-	no	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction to case, single leg conducting	Р		-	-	1.02		
Junction to case, both leg conducting	R _{thJC}		-	-	0.51	°C/W	
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.10	-		
Weight			-	30	-	g	
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)	
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)	
Case style				SOT-227			



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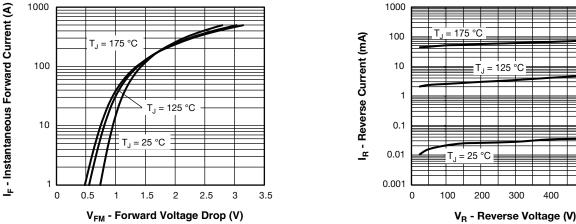
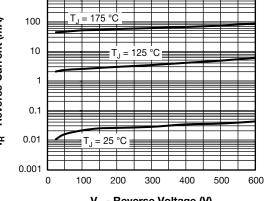
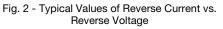


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Leg)





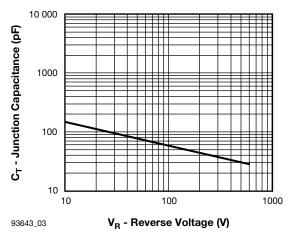


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

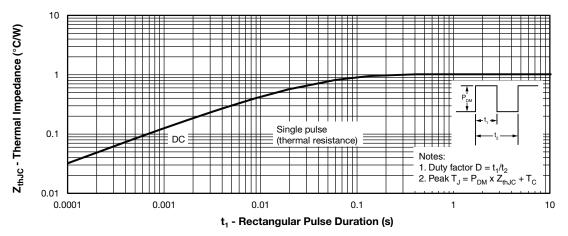
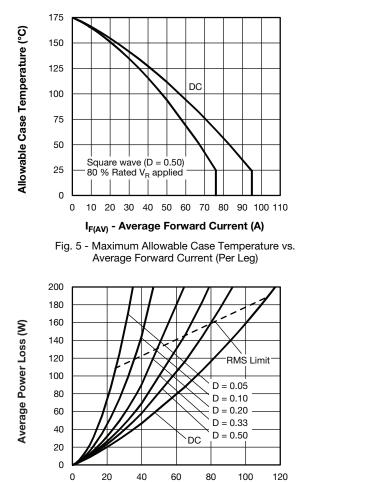


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

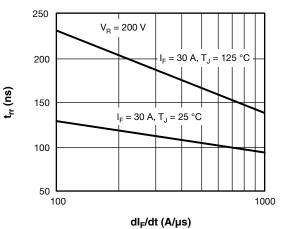
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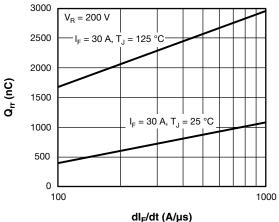
Average Forward Current - I_{F(AV)} (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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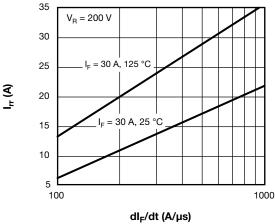


Fig. 9 - Typical Stored Current vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 18-Sep-2018

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Document Number: 93643

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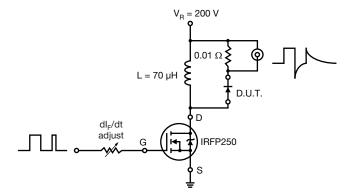


Fig. 10 - Reverse Recovery Parameter Test Circuit

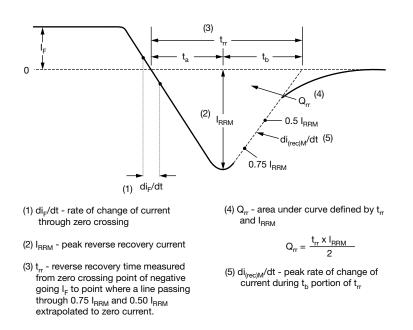


Fig. 11 - Reverse Recovery Waveform and Definitions





ORDERING INFORMATION TABLE

Device code	vs-	UF	L	80	F	Α	60
	1	2	3	4	5	6	7
	1 -	Visl	nay Sen	niconduc	ctors pro	oduct	
	2 -	- Ultrafast rectifier					
	3 -	Ultr	afast Pt	diffused	I, Low ∖	F	
	4 -	Cur	rent rati	ng (80 =	= 80 A)		
	5 -	Circ	cuit conf	iguratior	n (two s	eparate	diodes
	6 -	Pac	kage in	dicator (SOT-22	27 stanc	lard ins
	7 -	Vol	tage rati	ng (60 =	= 600 V))	

CIRCUIT CONFI	GURATION	
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two separate diodes, parallel pin-out	F	Lead Assignment

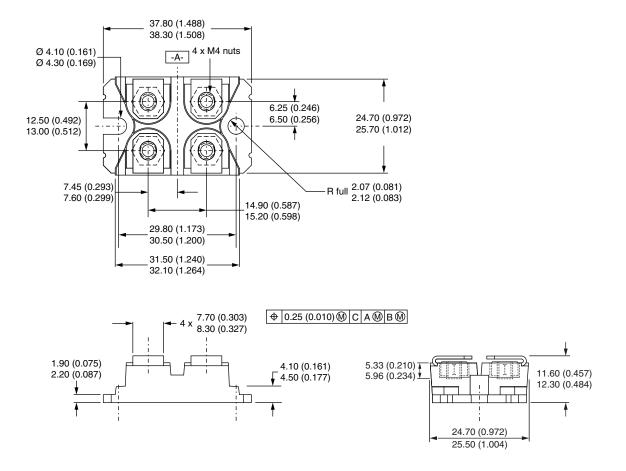
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95423					
Packaging information	www.vishay.com/doc?95425					





SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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